

S/N: 10/627,892

4/22/2005

DOCKET NO.: SUG-168-USAP

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Serial No.: 10/627,892

Confirmation No.: 3807

Applicant: Masayuki SHINOHARA, et al.

Art Unit: 2823

Filed: July 28, 2003

Examiner: Julio J. Maldonado

Docket No: SUG-168-USAP

Customer No: 28892

For: Method of Fabricating a Light Emitting Device, and Light Emitting Device

RESPONSE TO RESTRICTION REQUIREMENT


US Patent & Trademark Office
Customer Service Window, Mail Stop: RESTRICTION
Randolph Building
401 Dulany Street
Alexandria, VA 22314

Sir:

In response to the Office Action mailed March 31, 2005, Applicant hereby responds to the Restriction Requirement by electing the first species (directed to a light emitting device having a light emitting layer formed by a metal organic vapor phase epitaxy process and a current spreading layer formed by hydride vapor phase epitaxy). Applicant hereby identifies claims 25 - 27, 30, 32, 34, 36, 38 as being readable thereon.

It is respectfully submitted that the above is fully responsive to the Restriction Requirement. Further, it is respectfully submitted that this application is now in condition for examination on the merits, and early action and allowance thereof is accordingly requested.

Respectfully submitted


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Date: April 22, 2005

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